


InGaAs PIN Photodetectors

Wavespectrum Laser Inc.

Features: <ul style="list-style-type: none"> • Low noise, • Low dark current • Low terminal capacitance • Standard TO package, • Coaxial packages available • Receptacle packages available 	
Applications: <ul style="list-style-type: none"> • NIR photometry • Optical communication 	

Absolute Maximum Ratings

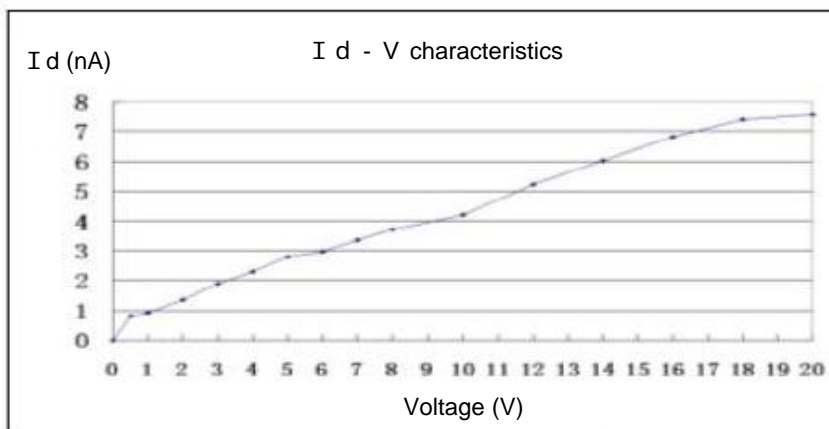
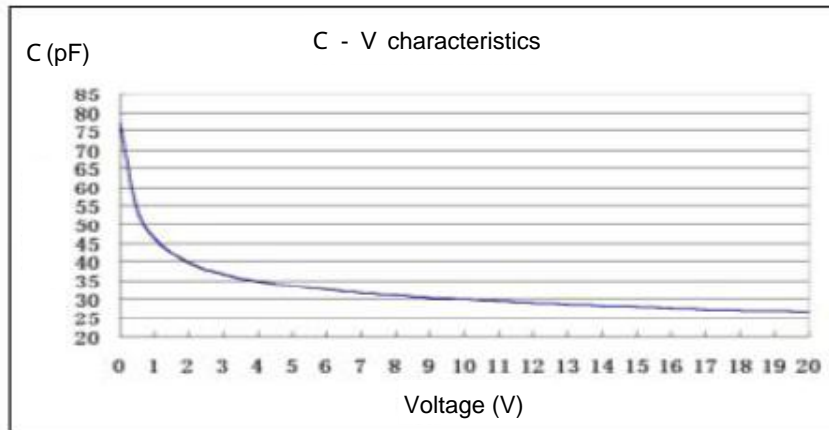
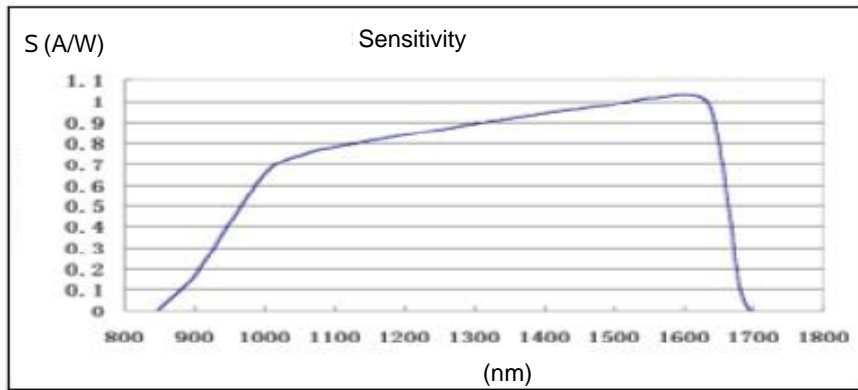
PARAMETER	SYMBOL	VALUE	UNIT
Operating Temperature	T_{op}	-40~+85	°C
Storage Temperature	T_{stg}	-40 ~ +125	°C
Reverse Voltage	V_r	30	V
Lead Soldering Temperature(10 sec.)	T_{is}	260	°C

Detailed specification

Specifications	Testing condition	WSPD-IGA-1000-1	Unit
Sensitive Area	----	Dia 1000	μm
Responsibility	=1310nm	≥ 0.80	A/W
	=1550nm	≥ 0.85	
Response Spectrum	-----	850~1700	nm
Dark Current (Typical)	$V_r=5V$	≤ 0.5	nA
Capacitance	$V_r=5V$	25	PF
Rise / Fall time	$V_r=5V$	20	ns
Bandwidth	3dB	----	GHz
Saturation power(Typical)	$V_r=5V$	≥ 2	mW



Test Data:



Package size

